DB4X314K

Silicon epitaxial planar type

For high speed switching circuits

Features

- Short reverse recovery time t_{rr}
- Small reverse current I_R
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)
- Marking Symbol: 4X

Basic Part Number

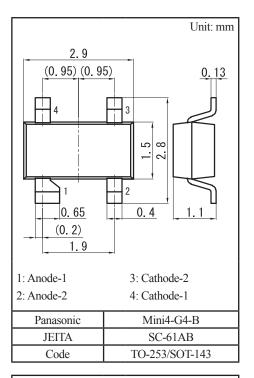
Dual DB2J314 (Parallel)

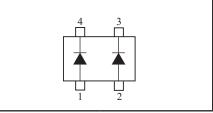
Packaging

DB4X314K0R Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

| Absolute Maximum Ratings $T_a = 25$ C | | | | | | | | | |
|---------------------------------------|------------------|-------------------|--------------------|----|--|--|--|--|--|
| Parameter | Symbol | Rating | Unit | | | | | | |
| Reverse voltage | | V _R | 30 | V | | | | | |
| Maximum peak reverse voltage | | V _{RM} | 30 | V | | | | | |
| Forward current | Single | т | 30 | mA | | | | | |
| | Double *1 | - I _F | 20 | | | | | | |
| Peak forward current | Single | т | 150 | mA | | | | | |
| | Double *1 | - I _{FM} | 110 | | | | | | |
| Junction temperature | | Tj | T _j 125 | | | | | | |
| Operating ambient temperature | | T _{opr} | -40 to +85 | °C | | | | | |
| Storage temperature | T _{stg} | -55 to +125 | °C | | | | | | |
| | | | | | | | | | |

Absolute Maximum Ratings $T_a = 25^{\circ}C$





Note) *1: Value of each diode in double diodes used.

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

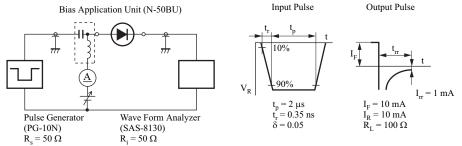
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------------|-----------------|--|-----|-----|------|------|
| Forward voltage | V _{F1} | $I_F = 1 \text{ mA}$ | | | 0.40 | v |
| | V _{F2} | $I_F = 30 \text{ mA}$ | | | 1.0 | |
| Reverse current | I _R | $V_R = 30 V$ | | | 300 | nA |
| Terminal capacitance | Ct | $V_{R} = 10 V, f = 1 MHz$ | | 1.5 | | pF |
| Reverse recovery time *1 | t _{rr} | $I_F = I_R = 10 \text{ mA}, I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$ | | 1.0 | | ns |

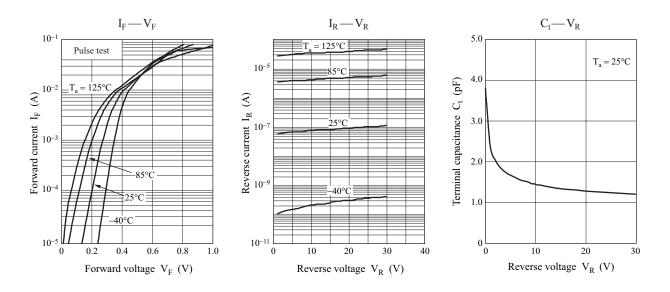
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. Absolute frequency of input and output is 2 \mbox{GHz}

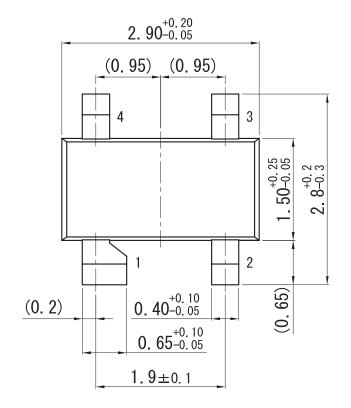
4. *1: t_{rr} measurement circuit

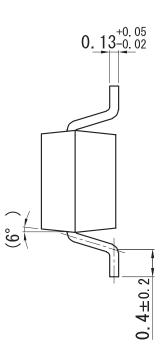


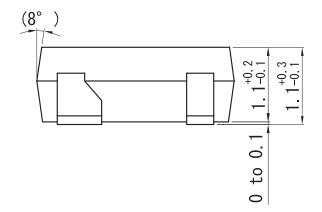


Unit: mm

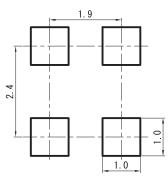
Mini4-G4-B







Land Pattern (Reference) (Unit: mm)



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